

SHINDENGEN

VR Series Power MOSFET

N-Channel Enhancement type

2SK1194
(F05E23)

230V 0.5A

FEATURES

- Applicable to 4V drive.
- The static $R_{ds(on)}$ is small.
- Built-in ZD for Gate Protection.

APPLICATION

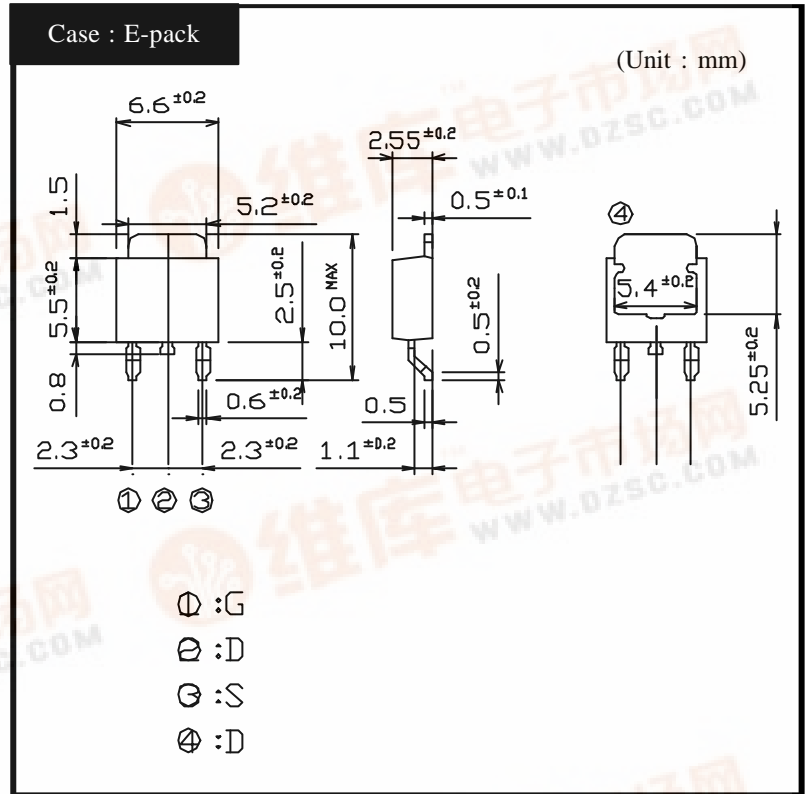
- DC/DC converters
- Power supplies of DC 12-24V input
- Product related to Integrated Service Digital Network

RATINGS

Absolute Maximum Ratings ($T_c = 25$)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55 ~ 150	
Channel Temperature	T_{ch}		150	
Drain-Source Voltage	V_{DSS}		230	V
Gate-Source Voltage	V_{GSS}		± 20	
Continuous Drain Current (DC)	I_D		0.5	A
Continuous Drain Current (Peak)	I_{DP}		1	
Continuous Source Current (DC)	I_S		0.5	
Total Power Dissipation	P_T		6	W

OUTLINE DIMENSIONS



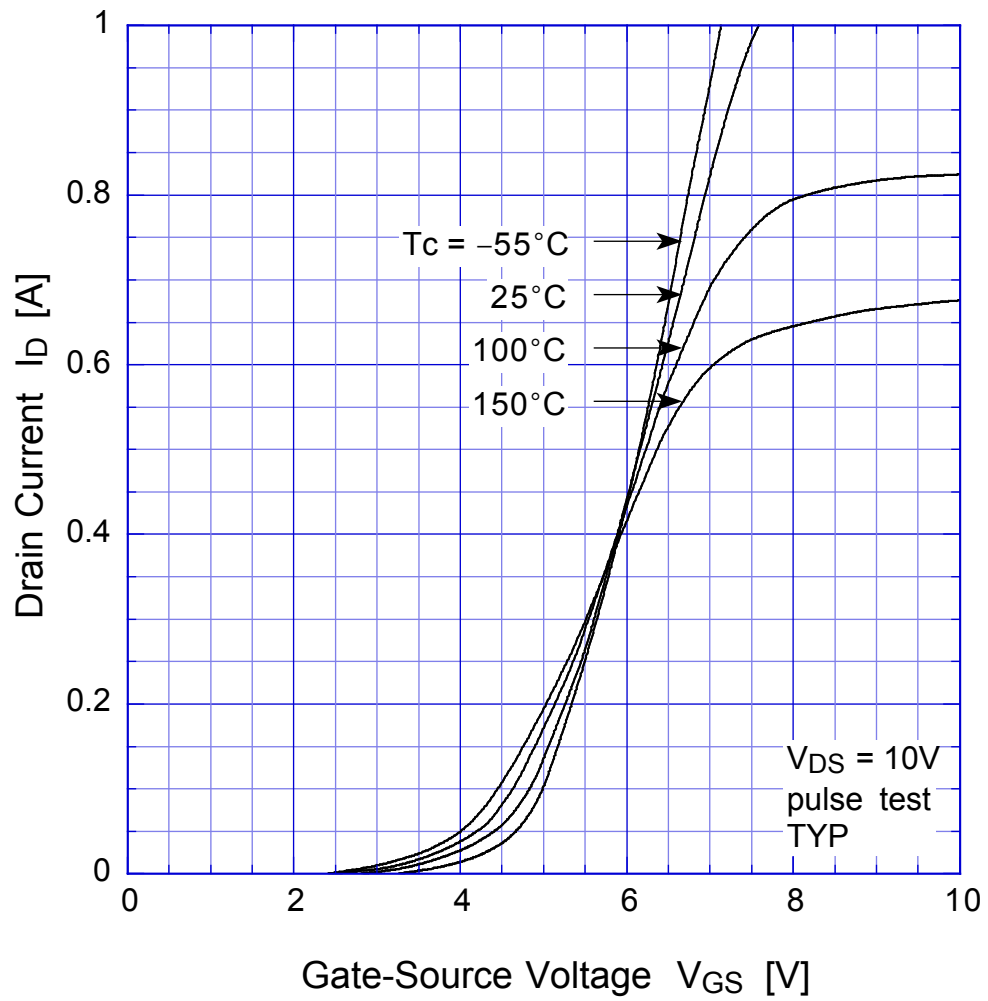
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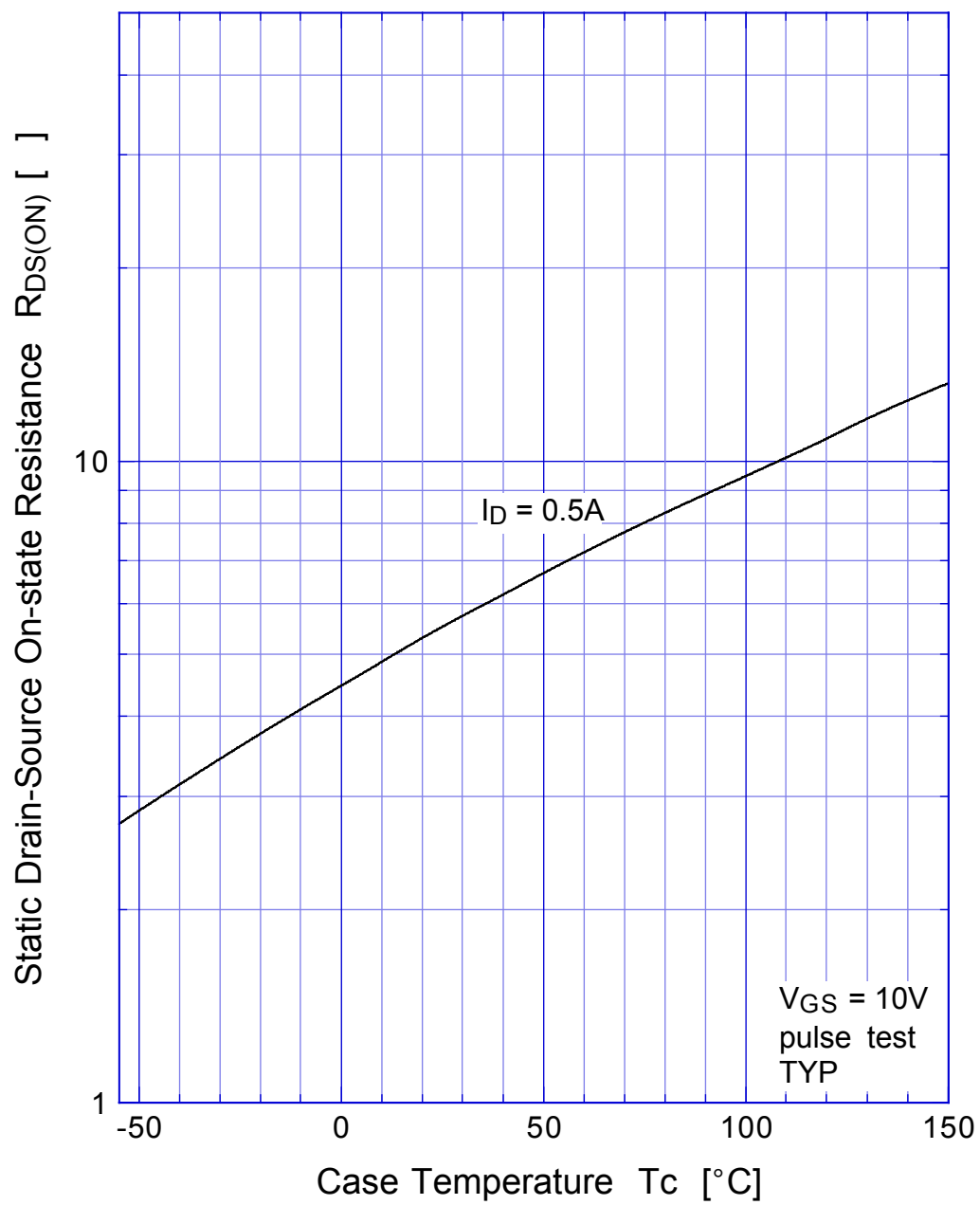
●Electrical Characteristics $T_c = 25^{\circ}\text{C}$

Item	Symbole	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 250 \mu\text{A}, V_{GS} = 0\text{V}$	230			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 230\text{V}, V_{GS} = 0\text{V}$			250	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$			± 0.1	
Forward Transconductance	g_{fs}	$I_D = 0.5\text{A}, V_{DS} = 10\text{V}$	0.2	0.4		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	$I_D = 0.5\text{A}, V_{GS} = 10\text{V}$		5.5	8	Ω
Gate Threshold Voltage	V_{TH}	$I_D = 0.2\text{mA}, V_{DS} = 10\text{V}$	2	3	4	V
Source-Drain Diode Forward Voltage	V_{SD}	$I_S = 0.5\text{A}, V_{GS} = 0\text{V}$			1.5	
Thermal Resistance	θ_{jc}	junction to case			20.8	$^{\circ}\text{C}/\text{W}$
Total Gate Charge	Q_g	$V_{GS} = 10\text{V}, I_D = 0.5\text{A}, V_{DD} = 200\text{V}$		2.7		nC
Input Capacitance	C_{iss}	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		45		pF
Reverse Transfer Capacitance	C_{rss}			4.5		
Output Capacitance	C_{oss}			30		
Turn-On Time	t_{on}	$I_D = 0.5\text{A}, V_{GS} = 10\text{V}, R_L = 200\Omega$		30	60	ns
Turn-Off Time	t_{off}			50	100	

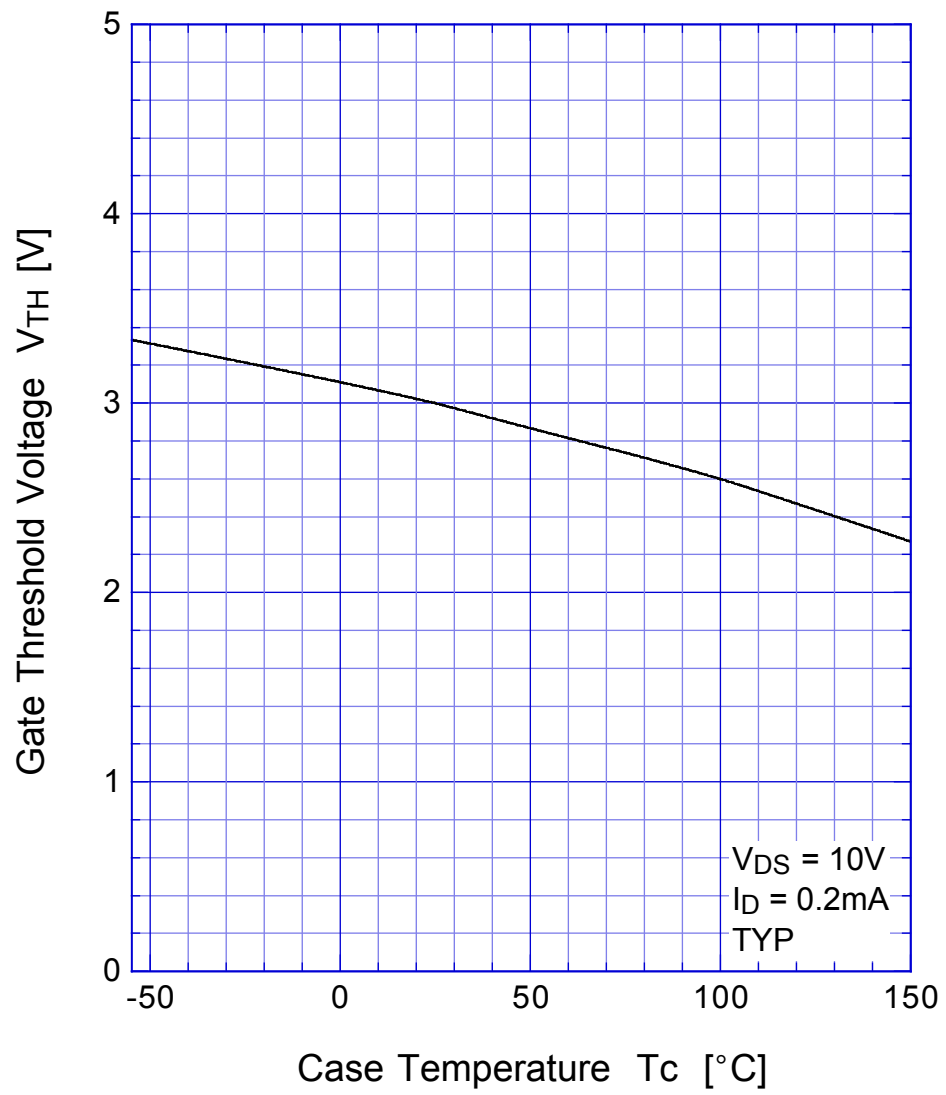
2SK1194 Transfer Characteristics



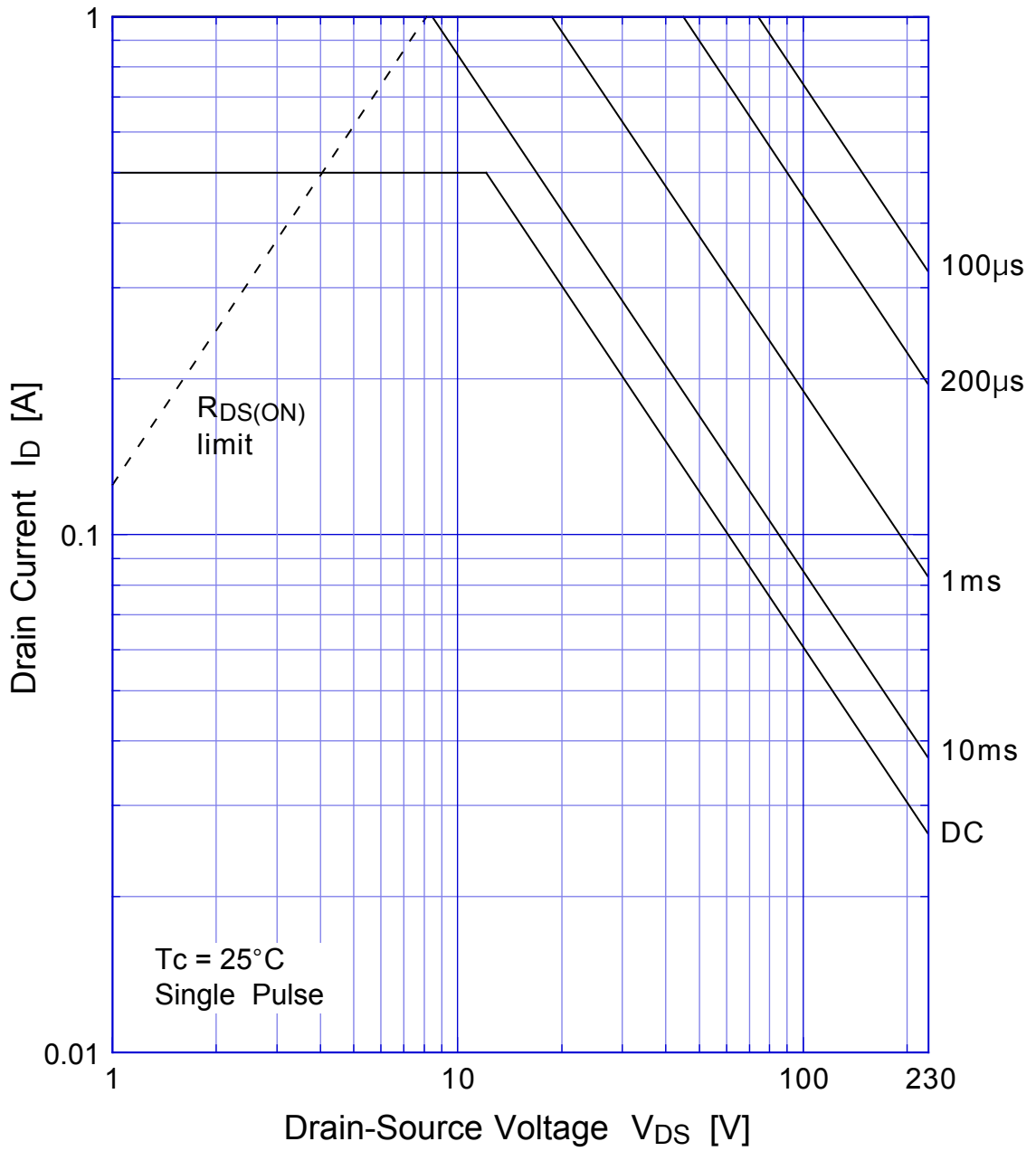
2SK1194 Static Drain-Source On-state Resistance



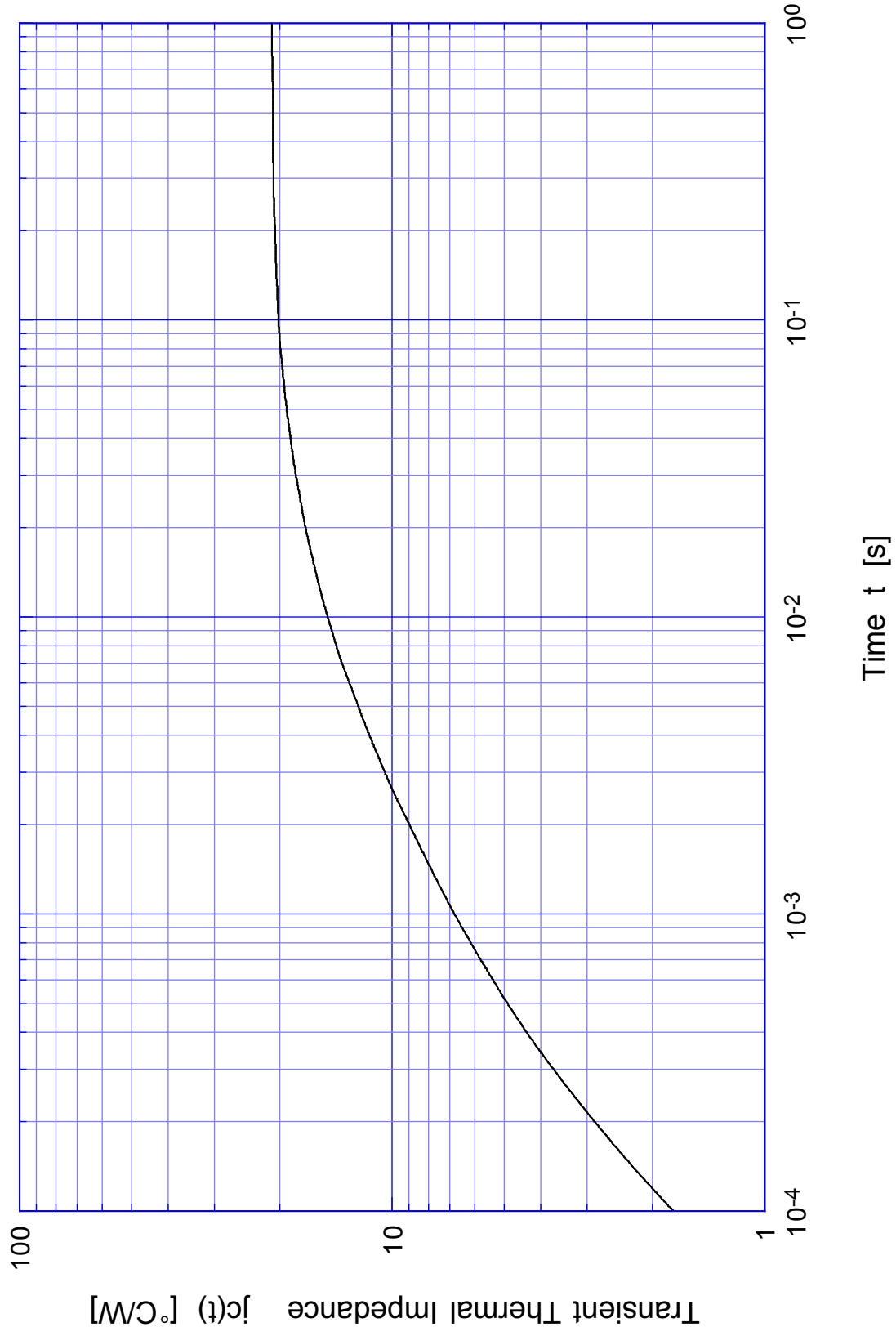
2SK1194 Gate Threshold Voltage



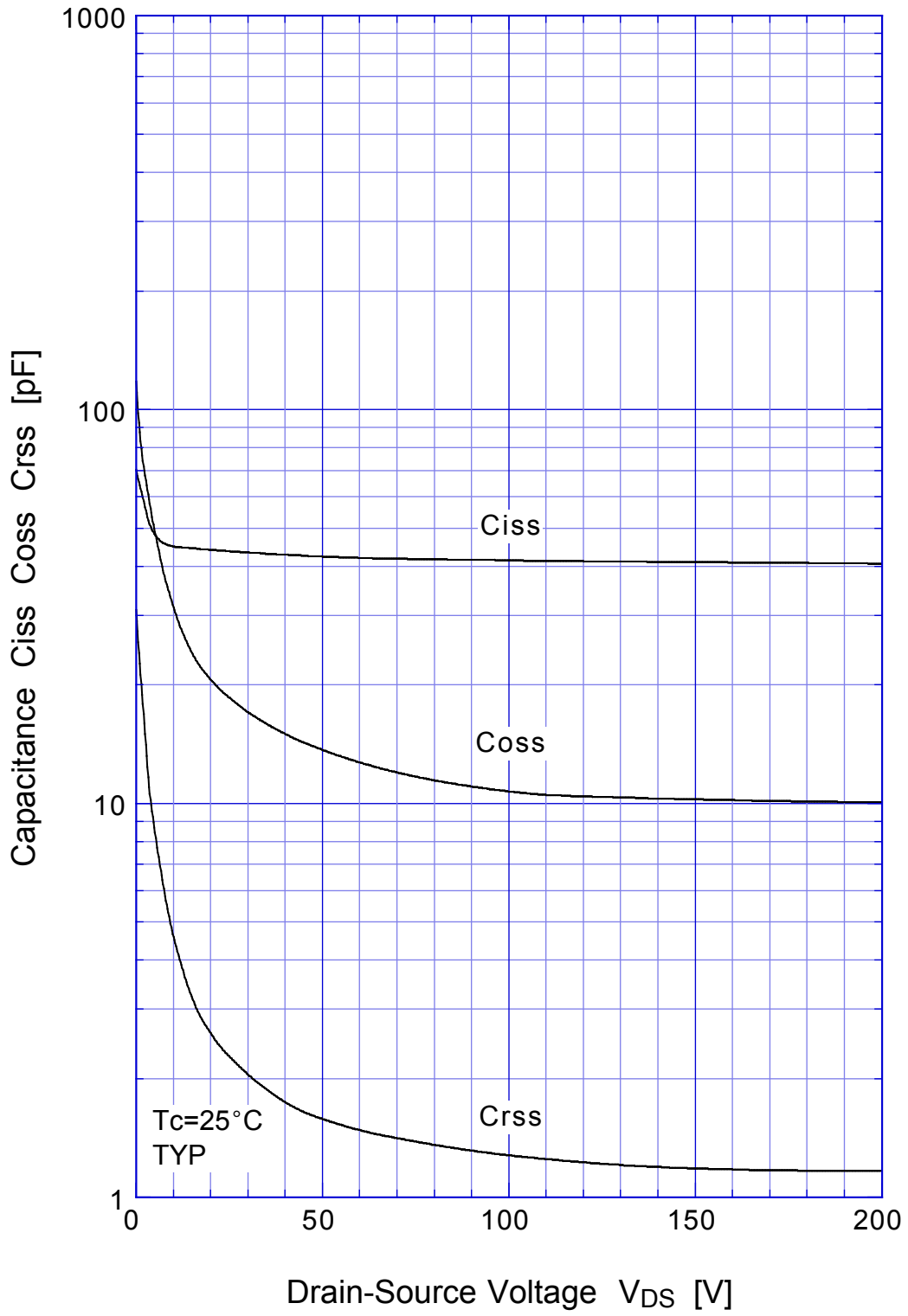
2SK1194 Safe Operating Area



2SK1194 Transient Thermal Impedance

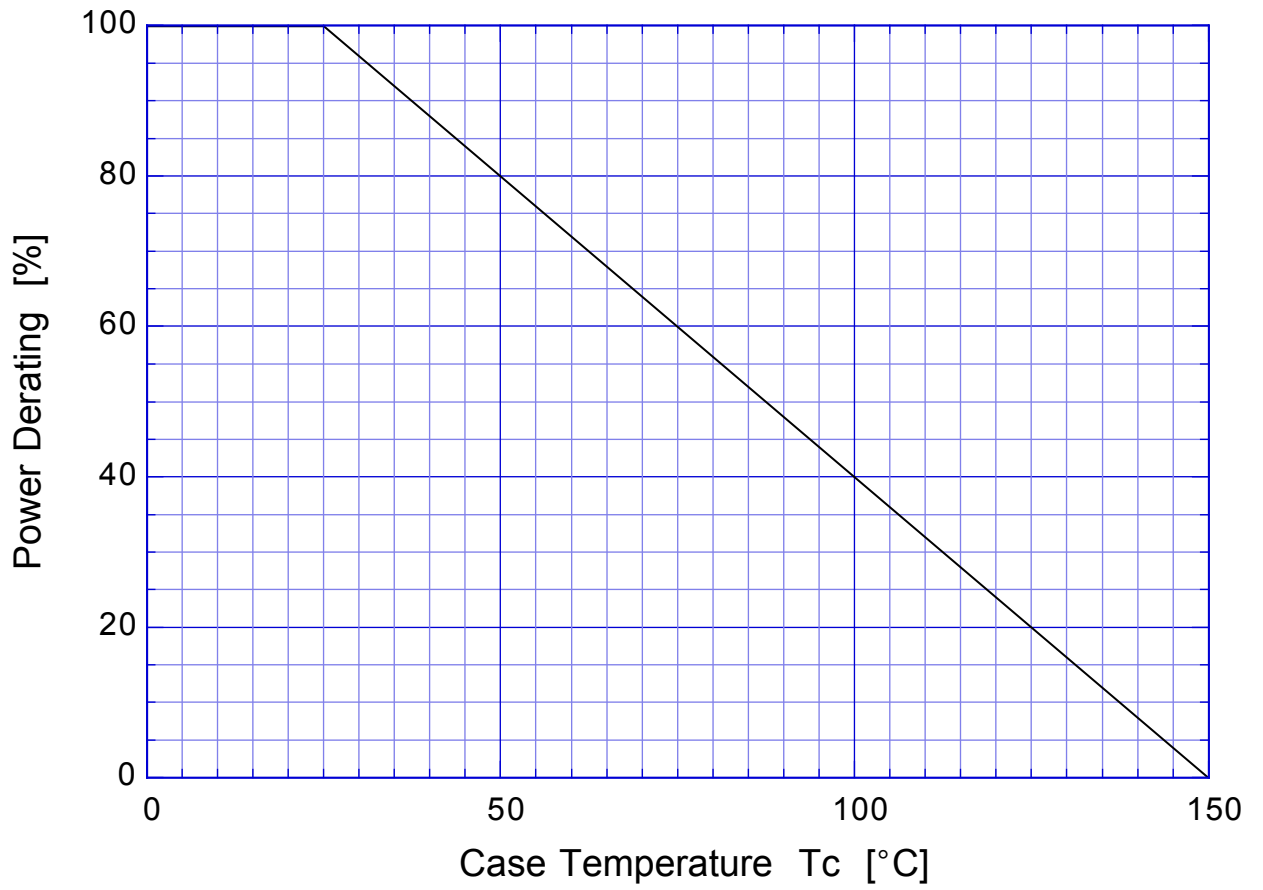


2SK1194 Capacitance



2SK1194

Power Derating



2SK1194 Gate Charge Characteristics

